MMSD103T1G, SMMSD103T1G

High Voltage Switching Diode

Features

- AEC-Q101 Qualified and PPAP Capable
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Continuous Reverse Voltage	V _R	250	V
Peak Forward Current	IF	200	mA
Peak Forward Surge Current	I _{FM(surge)}	625	mA

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Forward Power Dissipation, FR-5 Board (Note 1) @ T _A = 25°C Derate above 25°C	P _F	400 3.2	mW mW/°C
Thermal Resistance, Junction-to-Case	$R_{ heta JL}$	174	°C/W
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	492	°C/W
Junction and Storage Temperature Range	T _{J,} T _{stg}	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-5 = $1.0 \times 0.75 \times 0.062$ in.



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SOD-123 CASE 425 STYLE 1



MARKING DIAGRAM



JS = Device Code
M = Date Code
• = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
MMSD103T1G	SOD-123 (Pb-Free)	3,000 / Tape & Reel
SMMSD103T1G	SOD-123 (Pb-Free)	3,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

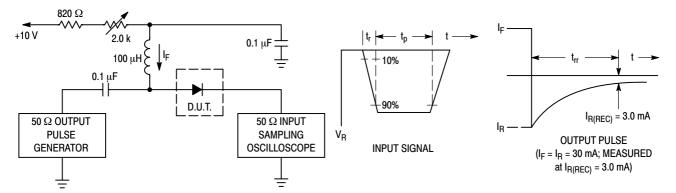
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^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MMSD103T1G, SMMSD103T1G

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Reverse Voltage Leakage Current (V _R = 200 V) (V _R = 200 V, T _J = 150°C)	I _R	- -	1.0 100	μΑ
Reverse Breakdown Voltage (I _{BR} = 100 μA)	V _(BR)	250	-	V
Forward Voltage (I _F = 100 mA) (I _F = 200 mA)	V _F	-	1000 1250	mV
Diode Capacitance (V _R = 0, f = 1.0 MHz)	C _D	-	5.0	pF
Reverse Recovery Time (IF = IR = 30 mA, RL = 100 Ω)	t _{rr}	-	50	ns



Notes: 1. A 2.0 $k\Omega$ variable resistor adjusted for a Forward Current (IF) of 30 mA.

2. Input pulse is adjusted so $I_{R(peak)}$ is equal to 30 mA.

3. t_p » t_{rr}

Figure 1. Recovery Time Equivalent Test Circuit

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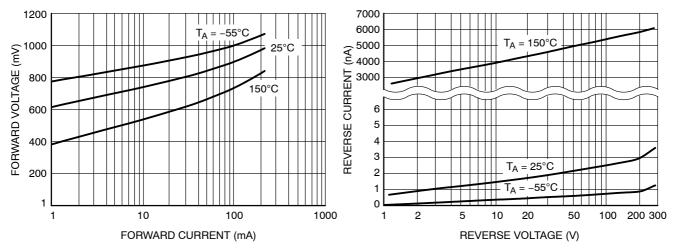


Figure 2. Forward Voltage

Figure 3. Reverse Leakage

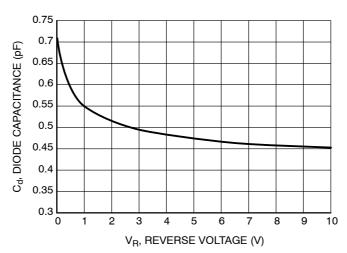


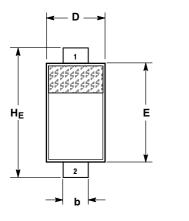
Figure 4. Diode Capacitance

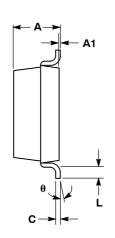


SOD-123 CASE 425-04 **ISSUE G**

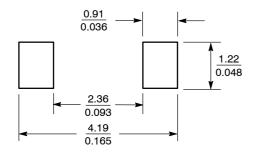
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SOLDERING FOOTPRINT*



SCALE 10:1

- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.94	1.17	1.35	0.037	0.046	0.053
A1	0.00	0.05	0.10	0.000	0.002	0.004
b	0.51	0.61	0.71	0.020	0.024	0.028
С			0.15			0.006
D	1.40	1.60	1.80	0.055	0.063	0.071
E	2.54	2.69	2.84	0.100	0.106	0.112
HE	3.56	3.68	3.86	0.140	0.145	0.152
L	0.25			0.010		
θ	0°		10°	0°		10°

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

= Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " •", may or may not be present.

STYLE 1: PIN 1. CATHODE 2. ANODE

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DESCRIPTION:	SOD-123		PAGE 1 OF 1	

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^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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